

RDN100N20FU6

RDN100N20FU6 Information

www.heisener.com	 RDN100N20FU6 Rohm Semiconductor Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 200V 10A TO-220FN TO-220-3 Full Pack For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RDN100N20FU6 Specifications

Manufacturer Part Number	RDN100N20FU6
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	543pF @ 10V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	35W (Tc)
Rds On (Max) @ Id, Vgs	360 mOhm @ 5A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220FN
Package / Case	TO-220-3 Full Pack
	Report errors?

RDN100N20FU6 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RDN100N20FU6 Payment Methods





If you have any question about RDN100N20FU6, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com